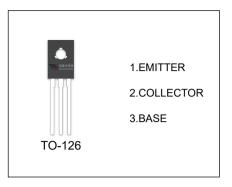


# 2SD669AL TRANSISTOR (NPN)

#### **FEATURES**

• Low Frequency Power Amplifier



#### **ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
2SD669AL	TO-126	Bulk	200pcs/Bag
2SD669AL-TU	TO-126	Tube	60pcs/Tube

### MAXIMUM RATINGS ( $T_a$ =25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	200	V
V <sub>CEO</sub>	Collector-Emitter Voltage	170	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.5	V
Ic	Collector Current	1	Α
Pc	Collector Power Dissipation	1	W
R <sub>θJA</sub>	Thermal Resistance from Junction to Ambient	125	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}$



## $T_a$ =25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100μA,I <sub>E</sub> =0	200			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA,I <sub>B</sub> =0	170			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 100μA,I <sub>C</sub> =0	6.5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =195V,I <sub>E</sub> =0			1	μA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =165V,I <sub>B</sub> =0			2	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V,I <sub>C</sub> =0			0.1	μA
DC ourrent sein	h <sub>FE(1)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =0.15A	100		320	
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	33			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =0.5A,I <sub>B</sub> =0.05A			0.9	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =0.15A			1.4	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V,I <sub>E</sub> =0, f=1MHz		14		pF
Transition frequency	f⊤	V <sub>CE</sub> =5V,I <sub>C</sub> =150mA		140		MHz

#### **CLASSIFICATION** of h<sub>FE(1)</sub>

RANK	С	D
RANGE	100-200	160-320



